

TO-220-3L/TO-220F Plastic-Encapsulate Diode

SBD20200CTB、SBDF20200CTB

SCHOTTKY BARRIER RECTIFIER

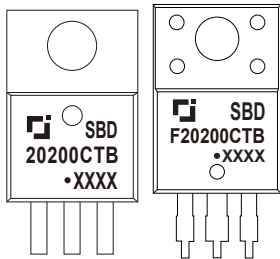
MAIN CHARACTERISTICS

I_O	20(10×2)A
V_{RRM}	200 V
T_J	150 °C
$V_{F(typ)}$	0.69V (@ $T_J=125^{\circ}C$)

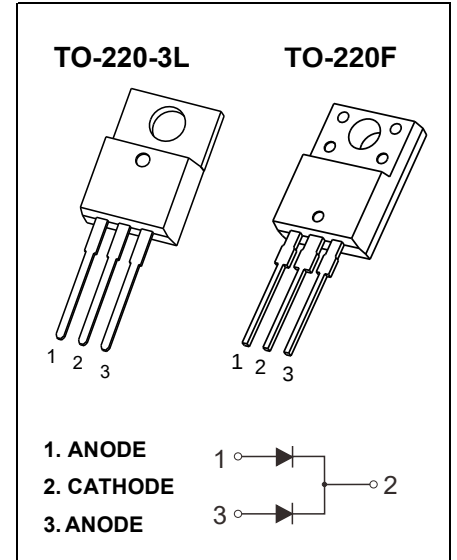
FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop

MARKING



SBD(F)20200CTB = Device code
Solid dot = Green molding compound device
if none, the normal device
XXXX = Code



MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	SBD		Unit
		20200CTB	F20200CTB	
V_{RRM}	Peak repetitive reverse voltage	200		V
V_{RWM}	Working peak reverse voltage			
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	140		V
I_O	Average rectified output current	20		A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200		A
$R_{\theta Jc}$	Thermal resistance from junction to case , $T_c=25^{\circ}C$	2.0	3.0	$^{\circ}C/W$
$R_{\theta JA}$	Thermal resistance from junction to ambient	75		$^{\circ}C/W$
T_J	Junction temperature	150		$^{\circ}C$
T_{stg}	Storage temperature	-55~+150		$^{\circ}C$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions		Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$		200			V
Reverse current	I_R	$V_R=200V$	$T_J=25^{\circ}C$		0.5	5.0	μA
			$T_J=125^{\circ}C$		1.0		mA
Forward voltage	V_F	$I_F=5A$	$T_J=25^{\circ}C$		0.78		V
			$T_J=125^{\circ}C$		0.63		V
		$I_F=10A$	$T_J=25^{\circ}C$		0.84	0.90	V
			$T_J=125^{\circ}C$		0.69		V

*Pulse test: pulse width $\leq 300\mu s$, duty cycles $\leq 2.0\%$.

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

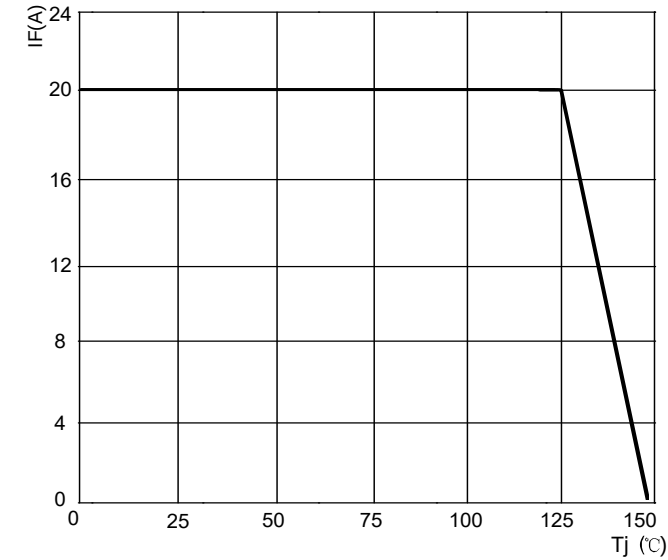


FIG.2: TYPICAL FORWARD CHARACTERISTICS

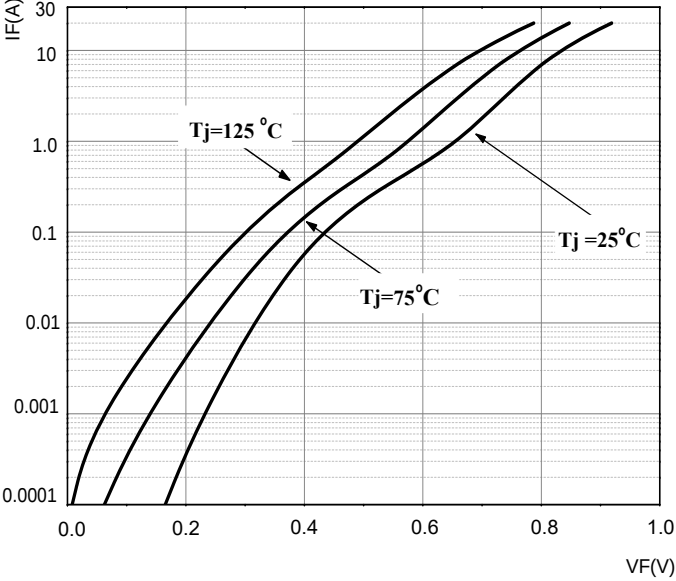


FIG.3: TOTAL CAPACITANCE DERATING CURVE

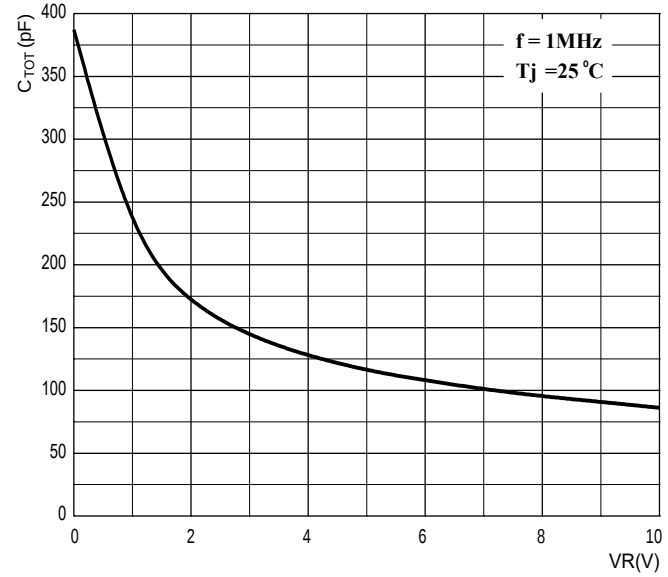
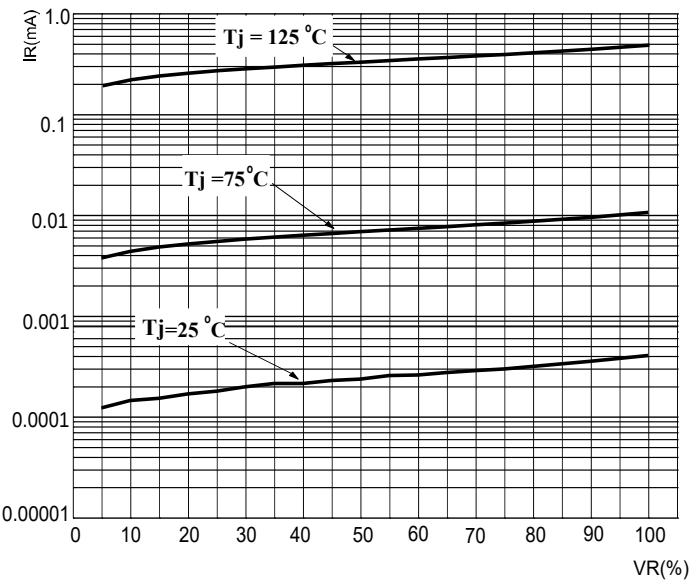


FIG.4: TYPICAL REVERSE CHARACTERISTICS



TO-220-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.450	4.750	0.175	0.187
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.300	0.500	0.012	0.020
c1	1.170	1.370	0.046	0.054
D	9.830	10.330	0.387	0.407
E	8.500	8.900	0.335	0.350
E1	12.050	12.650	0.474	0.498
e	2.540 TYP		0.100 TYP	
e1	4.900	5.200	0.192	0.205
F	2.540	2.940	0.100	0.116
h	0.100 TYP		0.004 TYP	
L	13.300	13.800	0.523	0.543
L1	3.540	3.940	0.139	0.155
Φ	3.735	3.935	0.147	0.155

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Rev. - 1.0